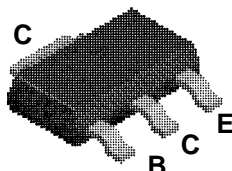


**FZT649**

**SOT-223**
**NPN Low Saturation Transistor**

These devices are designed with high current gain and low saturation voltage with collector currents up to 3A continuous.

**Absolute Maximum Ratings\***
 $T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	FZT649	Units
$V_{CEO}$	Collector-Emitter Voltage	25	V
$V_{CBO}$	Collector-Base Voltage	35	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_C$	Collector Current - Continuous	3	A
$T_J, T_{stg}$	Operating and Storage Junction Temperature Range	-55 to +150	$^\circ\text{C}$

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

**NOTES:**

- 1) These ratings are based on a maximum junction temperature of  $150^\circ\text{C}$ .
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

**Thermal Characteristics**
 $T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Characteristic	Max	Units
		FZT649	
$P_D$	Total Device Dissipation	2	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	62.5	$^\circ\text{C/W}$

**NPN Low Saturation Transistor**

(continued)

**Electrical Characteristics** $T_A = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
<b>OFF CHARACTERISTICS</b>					
$BV_{CEO}$	Collector-Emitter Breakdown Voltage	$I_C = 10\text{ mA}$	25		V
$BV_{CBO}$	Collector-Base Breakdown Voltage	$I_C = 100\text{ }\mu\text{A}$	35		V
$BV_{EBO}$	Emitter-Base Breakdown Voltage	$I_E = 100\text{ }\mu\text{A}$	5		V
$I_{CBO}$	Collector Cutoff Current	$V_{CB} = 30\text{ V}$ $V_{CB} = 30\text{ V}, T_A = 100^\circ\text{C}$		100 10	nA $\mu\text{A}$
$I_{EBO}$	Emitter Cutoff Current	$V_{EB} = 4\text{ V}$		100	nA
<b>ON CHARACTERISTICS*</b>					
$h_{FE}$	DC Current Gain	$I_C = 50\text{ mA}, V_{CE} = 2\text{ V}$ $I_C = 1\text{ A}, V_{CE} = 2\text{ V}$ $I_C = 2\text{ A}, V_{CE} = 2\text{ V}$ $I_C = 6\text{ A}, V_{CE} = 2\text{ V}$	70 100 75 15	300	-
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C = 1\text{ A}, I_B = 100\text{ mA}$ $I_C = 3\text{ A}, I_B = 300\text{ mA}$		300 600	mV
$V_{BE(sat)}$	Base-Emitter Saturation Voltage	$I_C = 1\text{ A}, I_B = 100\text{ mA}$		1.25	V
$V_{BE(on)}$	Base-Emitter On Voltage	$I_C = 1\text{ A}, V_{CE} = 2\text{ V}$		1	V
<b>SMALL SIGNAL CHARACTERISTICS</b>					
$C_{obo}$	Output Capacitance	$V_{CB} = 10\text{ V}, I_E = 0, f = 1\text{ MHz}$		50	pF
$f_T$	Transition Frequency	$I_C = 100\text{ mA}, V_{CE} = 5\text{ V}, f = 100\text{ MHz}$	150		-

\*Pulse Test: Pulse Width  $\leq 300\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

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